

# PNP General Purpose Transistor

## **NST3906F3T5G**

The NST3906F3T5G device is a spin-off of our popular SOT-23/SOT-323/SOT-563/SOT-963 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-1123 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

#### **Features**

- h<sub>FE</sub>, 100-300
- Low  $V_{CE(sat)}$ ,  $\leq 0.4 \text{ V}$
- Reduces Board Space
- This is a Pb-Free Device

#### **MAXIMUM RATINGS**

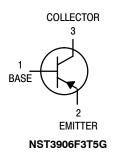
Rating	Symbol	Value	Unit
Collector - Emitter Voltage	$V_{CEO}$	-40	Vdc
Collector - Base Voltage	$V_{CBO}$	-40	Vdc
Emitter – Base Voltage	$V_{EBO}$	-5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	-200	mAdc

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub> (Note 1)	290 2.3	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 1)	432	°C/W
Total Device Dissipation, T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub> (Note 2)	347 2.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>0JA</sub> (Note 2)	360	°C/W
Thermal Resistance, Junction-to-Lead 3	R <sub>ΨJL</sub> (Note 2)	143	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. 100 mm<sup>2</sup> 1 oz, copper traces.
- 2. 500 mm<sup>2</sup> 1 oz, copper traces.





SOT-1123 CASE 524AA STYLE 1

#### **MARKING DIAGRAM**



3 = Device Code M = Date Code

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NST3906F3T5G	SOT-1123 (Pb-Free)	8000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

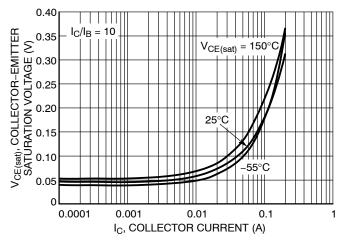
### **NST3906F3T5G**

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit	
OFF CHARACTE	RISTICS	•		•	•	
Collector - Emitter	V <sub>(BR)CEO</sub>	-40	-	Vdc		
Collector - Base B	reakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	-40	-	Vdc	
Emitter – Base Bre	akdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	-5.0	-	Vdc	
Collector Cutoff Co	I <sub>CEX</sub>	-	-50	nAdc		
ON CHARACTE	RISTICS (Note 3)				•	
$(I_C = -1.0 \text{ mAdc})$ $(I_C = -10 \text{ mAdc})$ $(I_C = -50 \text{ mAdc})$	$V_{CE} = -1.0 \text{ Vdc}$ $V_{CE} = -1.0 \text{ Vdc}$ $V_{CE} = -1.0 \text{ Vdc}$ $V_{CE} = -1.0 \text{ Vdc}$ $V_{CE} = -1.0 \text{ Vdc}$	h <sub>FE</sub>	60 80 100 60 30	- 300 - -	-	
$(I_C = -10 \text{ mAdc},$	Saturation Voltage $I_B = -1.0 \text{ mAdc}$ $I_B = -5.0 \text{ mAdc}$	V <sub>CE(sat)</sub>	- -	-0.25 -0.4	Vdc	
Base – Emitter Saturation Voltage ( $I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ( $I_C = -50$ mAdc, $I_B = -5.0$ mAdc)		V <sub>BE(sat)</sub>	-0.65 -	-0.85 -0.95	Vdc	
SMALL-SIGNAL	. CHARACTERISTICS	•		•	•	
Current - Gain - B	andwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	f <sub>T</sub>	250	-	MHz	
Output Capacitance (V <sub>CB</sub> = -5.0 V, I <sub>E</sub> = 0 mA, f = 1.0 MHz)		C <sub>obo</sub>	_	4.5	pF	
Input Capacitance (V <sub>EB</sub> = -0.5 V, I <sub>E</sub> = 0 mA, f = 1.0 MHz)		C <sub>ibo</sub>	-	10.0	pF	
Noise Figure ( $V_{CE}=-5.0~Vdc,~I_{C}=-100~\mu Adc,~R_{S}=1.0~k\Omega,~f=1.0~kHz$ )		NF	-	4.0	dB	
SWITCHING CH	ARACTERISTICS	•	•	•	1	
Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc})$	t <sub>d</sub>	-	35		
Rise Time	(I <sub>C</sub> = -10 mAdc, I <sub>B1</sub> = -1.0 mAdc)	t <sub>r</sub>	_	35	ns	
Storage Time	$(V_{CC} = -3.0 \text{ Vdc}, I_{C} = -10 \text{ mAdc})$	t <sub>s</sub>	_	250		

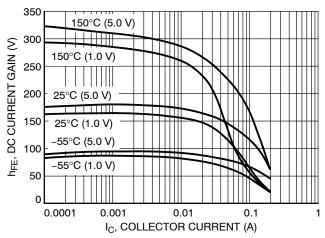
<sup>3.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu s;$  Duty Cycle  $\leq$  2.0%.

Fall Time



 $(I_{B1} = I_{B2} = -1.0 \text{ mAdc})$ 

Figure 1. Collector Emitter Saturation Voltage vs.
Collector Current



ns

50

Figure 2. DC Current Gain vs. Collector Current

### **NST3906F3T5G**

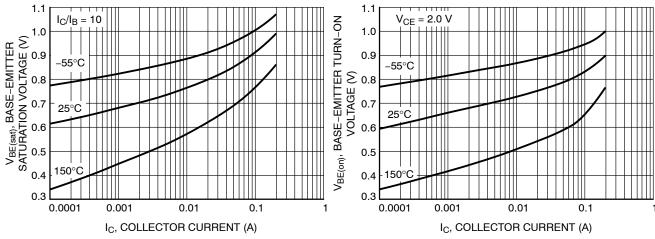


Figure 3. Base Emitter Saturation Voltage vs. Collector Current

Figure 4. Base Emitter Turn-On Voltage vs.
Collector Current

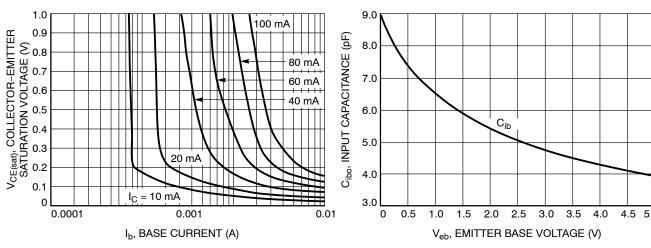


Figure 5. Saturation Region

Figure 6. Input Capacitance

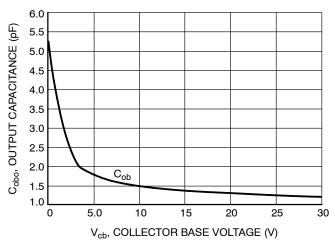


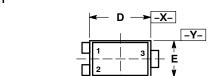
Figure 7. Output Capacitance

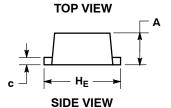


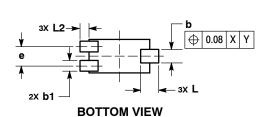


SOT-1123 CASE 524AA ISSUE C

**DATE 29 NOV 2011** 







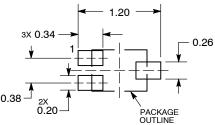
#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			
DIM	MIN MAX			
Α	0.34	0.40		
b	0.15	0.28		
b1	0.10	0.20		
С	0.07	0.17		
D	0.75	0.85		
Е	0.55	0.65		
е	0.35	0.40		
HE	0.95	1.05		
L	0.185 REF			
L2	0.05 0.15			

#### **SOLDERING FOOTPRINT\***



**DIMENSIONS: MILLIMETERS** 

## **GENERIC MARKING DIAGRAM\***



Χ = Specific Device Code

М = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. GATE
<ol><li>EMITTER</li></ol>	2. N/C	2. ANODE	<ol><li>CATHODE</li></ol>	<ol><li>SOURCE</li></ol>
3. COLLECTOR	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE</li></ol>	3. ANODE	3. DRAIN

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DESCRIPTION: SOT-1123 3-LEAD 1 0x0 6x0 37 0 35P		PAGE 1 OF 1	

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